

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
60V	50mΩ @ V _{GS} = 10V	24A
00 v	65mΩ @ V _{GS} = 4.5V	21A

Features and Benefits

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching—Ensures More Reliable and Robust End Application
- Low R_{DS(ON)}—Minimizes Power Losses
- Low Q_G—Minimizes Switching Losses
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

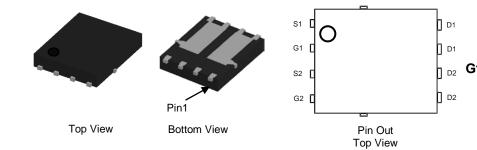
Description and Applications

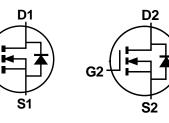
This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

Mechanical Data

- Case: PowerDI[®]5060-8 (Type C)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)





Equivalent Circuit

Ordering Information (Note 5)

Part Number	Case	Packaging
DMNH6042SPDQ-13	PowerDI5060-8 (Type C)	2500/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

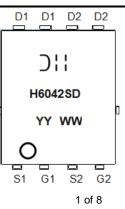
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



>;; = Manufacturer's Marking H6042SD = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 18 = 2018) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	60	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 7) V_{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	Ι _D	5.7 4.6	A
Continuous Drain Current (Note 8) V_{GS} = 10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	Ι _D	24 17	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	32	A		
Maximum Continuous Body Diode Forward Current	ls	24	A		
Avalanche Current (Note 9) L = 10mH	I _{AS}	3.5	A		
Avalanche Energy (Note 9) L = 10mH			E _{AS}	65	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)		PD	1.2	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Davi	105	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	R _{ÐJA}	54	
Total Power Dissipation (Note 7)		PD	2.5	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	Devi	51	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	t<10s	R _{ÐJA}	26	
Thermal Resistance, Junction to Case (Note 8)	Rejc	3.5		
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

6. Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided. Notes:

Device mounted on FR-4 substrate PCB, 202 copper, with thermal bias to bottom layer 1-inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.



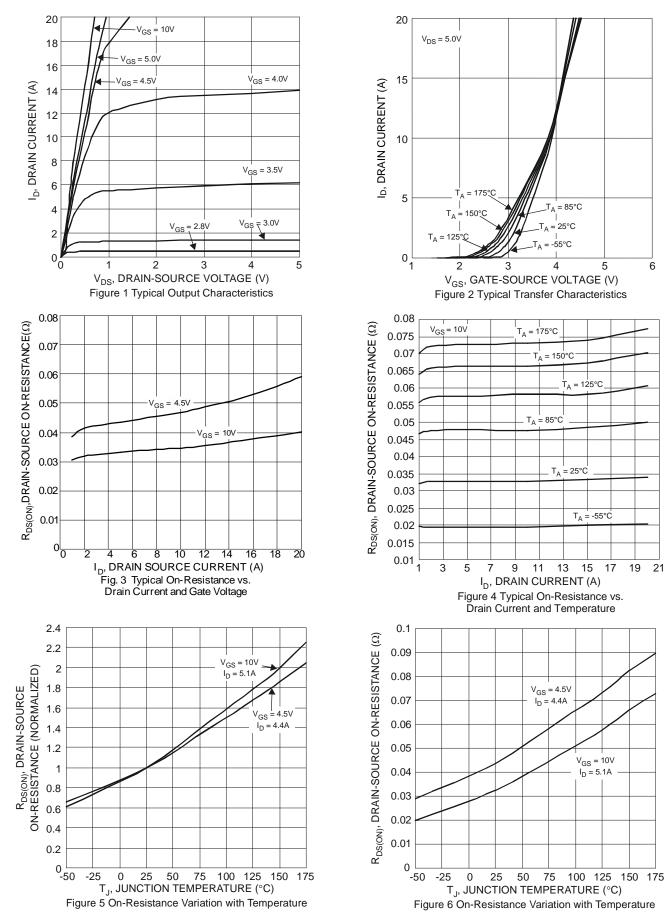
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 10)					1	T	
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	IDSS	—	—	1	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	—	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 10)	· · · · ·					-	
Gate Threshold Voltage	V _{GS(TH)}	1.0	—	3.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	D =a(a))	—	34	50	mΩ	$V_{GS} = 10V, I_D = 5.1A$	
	Rds(on)	—	45	65		$V_{GS} = 4.5V, I_D = 4.4A$	
Diode Forward Voltage	V _{SD}	—	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 2.6A$	
DYNAMIC CHARACTERISTICS (Note 11)							
Input Capacitance	CISS	—	584	—	pF		
Output Capacitance	Coss	—	83	_	pF	− V _{DS} = 25V, V _{GS} = 0V, − f = 1.0MHz	
Reverse Transfer Capacitance	C _{RSS}	—	24	—	pF		
Gate Resistance	R _G	_	3.8	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge ($V_{GS} = 4.5V$)	Q_G	_	4.2	—	nC		
Total Gate Charge (V _{GS} = 10V)	Q_G	_	8.8	—	nC	V _{DS} = 44V, I _D = 5.2A	
Gate-Source Charge	Q _{GS}	—	1.8	—	nC	$V_{DS} = 44V, ID = 3.2A$	
Gate-Drain Charge	Q _{GD}	—	1.8	—	nC		
Turn-On Delay Time	t _{D(ON)}	_	3.4	—	ns		
Turn-On Rise Time	t _R	_	1.9	—	ns	$V_{GS} = 10V, V_{DS} = 30V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	10.1	_	ns	$R_G = 6\Omega, I_D = 1A$	
Turn-Off Fall Time	t _F	_	4.5	—	ns		
Body Diode Reverse Recovery Time	t _{RR}	_	12.9	_	ns	$I_F = 2.6A$, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Q _{RR}	_	5.4	—	nC	I _F = 2.6A, di/dt = 100A/µs	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

DMNH6042SPDQ



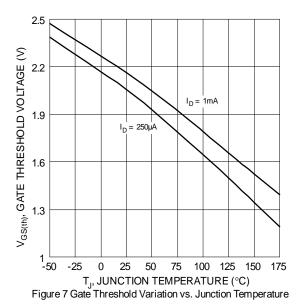


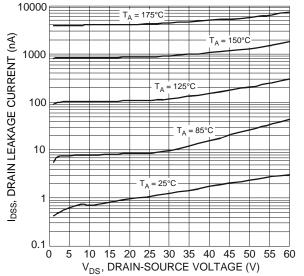
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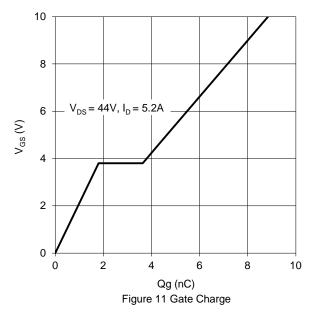


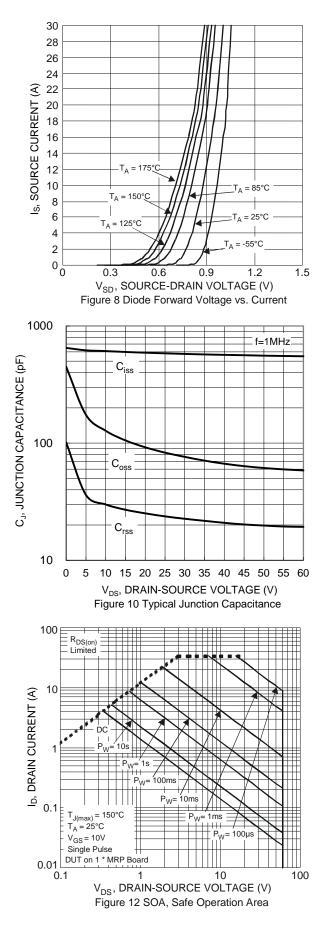






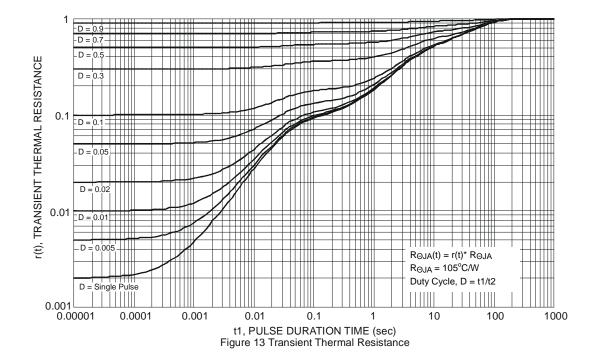










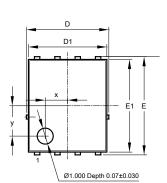


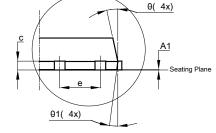


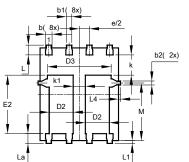
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

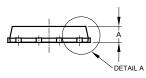
PowerDI5060-8 (Type C)







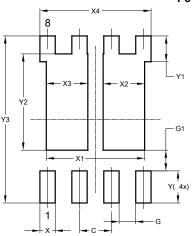




PowerDI5060-8 (Type C)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05	0.02		
b	0.33	0.51	0.41		
b1	0.300	0.366	0.333		
b2	0.20	0.35	0.25		
С	0.23	0.33	0.277		
D	5	5.15 BSC	2		
D1	4.85	4.95	4.90		
D2	1.40	1.60	1.50		
D3	—	_	3.98		
Е	6	6.15 BSC			
E1	5.75	5.85	5.80		
E2	3.56	3.76	3.66		
е		1.27BSC	;		
k	—		1.27		
k1	0.56	—	-		
L	0.51	0.71	0.61		
La	0.51	0.71	0.61		
L1	0.05	0.20	0.175		
L4	_	—	0.125		
Μ	3.50	3.71	3.605		
x	_	—	1.400		
у		_	1.900		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8 (Type C)

Dimensions	Value		
	(in mm)		
C	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	3.910		
X2	1.650		
X3	1.650		
X4	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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